

# PSMN020-30MLC

N-channel 30 V 18.1 m $\Omega$  logic level MOSFET in LFPAK33 using TrenchMOS Technology

4 September 2012

**Product data sheet** 

### 1. Product profile

#### 1.1 General description

Logic level enhancement mode N-channel MOSFET in LFPAK33 package. This product is designed and qualified for use in a wide range of industrial, communications and domestic equipment.

#### 1.2 Features and benefits

- Low parasitic inductance and resistance
- Optimised for 4.5V Gate drive utilising Superjunction technology
- Ultra low QG, QGD, and QOSS for high system efficiencies at low and high loads

### 1.3 Applications

- DC-to-DC converters
- Load switching
- Synchronous buck regulator

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C	-	-	30	V
I <sub>D</sub>	drain current	T <sub>mb</sub> = 25 °C; V <sub>GS</sub> = 10 V; <u>Fig. 1</u>	-	-	31.8	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	-	-	33	W
Tj	junction temperature		-55	-	175	°C
Static charact	eristics			'	'	,
R <sub>DSon</sub>	drain-source on-state resistance	$V_{GS}$ = 4.5 V; $I_D$ = 5 A; $T_j$ = 25 °C; Fig. 10	-	20.5	27	mΩ
		$V_{GS}$ = 10 V; $I_D$ = 5 A; $T_j$ = 25 °C; <u>Fig. 10</u>	-	14.7	18.1	mΩ
Dynamic char	acteristics			'	'	
$Q_{GD}$	gate-drain charge	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 5 A; V <sub>DS</sub> = 15 V; Fig. 12; Fig. 13	-	1.7	-	nC
Q <sub>G(tot)</sub>	total gate charge	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 5 A; V <sub>DS</sub> = 15 V; Fig. 12; Fig. 13	-	4.6	-	nC



### 2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		D I
2	S	source		
3	S	source		G—U: 4
4	G	gate		mbb076 S
mb	D	mounting base; connected to drain	LFPAK33 (SOT1210)	

### 3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PSMN020-30MLC	LFPAK33	Plastic single ended surface mounted package (LFPAK33); 4 leads	SOT1210			

## 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C	-	30	V
$V_{GS}$	gate-source voltage		-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 25 °C; <u>Fig. 1</u>	-	31.8	Α
		V <sub>GS</sub> = 10 V; T <sub>mb</sub> = 100 °C; <u>Fig. 1</u>	-	22.5	Α
I <sub>DM</sub>	peak drain current	pulsed; $t_p \le 10 \mu s$ ; $T_{mb} = 25 ^{\circ}C$ ; Fig. 4	-	127	Α
P <sub>tot</sub>	total power dissipation	T <sub>mb</sub> = 25 °C; <u>Fig. 2</u>	-	33	W
T <sub>stg</sub>	storage temperature		-55	175	°C
Tj	junction temperature		-55	175	°C
T <sub>sld(M)</sub>	peak soldering temperature		-	260	°C
V <sub>ESD</sub>	electrostatic discharge voltage	MM (JEDEC JESD22-A115)	130	-	V
Source-drain o	diode				
I <sub>S</sub>	source current	T <sub>mb</sub> = 25 °C	-	27.4	Α
I <sub>SM</sub>	peak source current	pulsed; $t_p \le 10 \ \mu s$ ; $T_{mb} = 25 \ ^{\circ}C$	-	127	Α

Symbol	Parameter	Conditions	Min	Max	Unit
Avalanche rug	gedness				
E <sub>DS(AL)</sub> S	non-repetitive drain-source avalanche energy	$V_{GS}$ = 10 V; $T_{j(init)}$ = 25 °C; $I_D$ = 31 A; $V_{sup} \le$ 30 V; $R_{GS}$ = 50 Ω; unclamped; Fig. 3	-	7.7	mJ

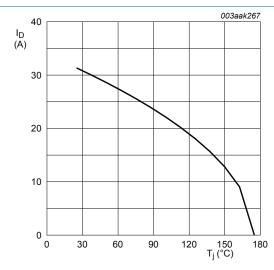


Fig. 1. Continuous drain current as a function of mounting base temperature

$$V_{GS} \ge 10V$$

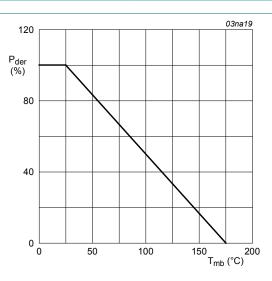


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\%$$

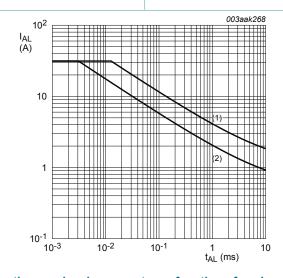
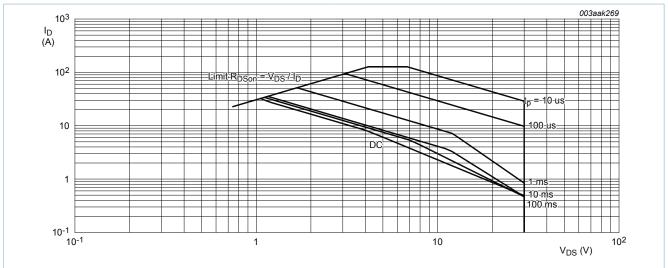


Fig. 3. Single pulse avalanche rating; avalanche current as a function of avalanche time

(1) 
$$T_{j (init)} = 25^{\circ}C$$
; (2)  $T_{j (init)} = 100^{\circ}C$ 



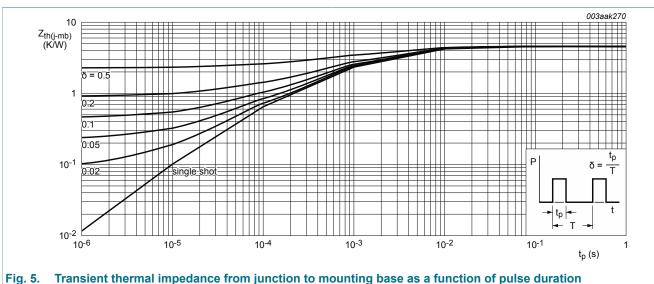
Safe operating area; continuous and peak drain currents as a function of drain-source voltage

 $T_{mb} = 25^{\circ}C$ ;  $I_{DM}$  is a single pulse

### Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 5	-	4.32	4.56	K/W



### 6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	cteristics		·			
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = 13.5 A; $V_{GS}$ = 0 V; $T_{j(init)}$ = 25 °C; $t_p \le 50 \ \mu s$	34	-	-	V
		$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 ^{\circ}C$	30	-	-	V
		I <sub>D</sub> = 250 μA; V <sub>GS</sub> = 0 V; T <sub>j</sub> = -55 °C	27	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$I_D$ = 1 mA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	1.05	1.62	1.95	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature		-	-3.5	-	mV/k
I <sub>DSS</sub>	drain leakage current	$V_{DS} = 30 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$	-	-	1	μA
		V <sub>DS</sub> = 30 V; V <sub>GS</sub> = 0 V; T <sub>j</sub> = 150 °C	-	-	100	μA
I <sub>GSS</sub> gate leakage current	gate leakage current	V <sub>GS</sub> = 16 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	100	nA
		V <sub>GS</sub> = -16 V; V <sub>DS</sub> = 0 V; T <sub>j</sub> = 25 °C	-	-	100	nA
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 25 °C; Fig. 10	-	20.5	27	mΩ
		V <sub>GS</sub> = 4.5 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 150 °C; Fig. 10; Fig. 11	-	-	43.2	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	14.7	18.1	mΩ
		V <sub>GS</sub> = 10 V; I <sub>D</sub> = 5 A; T <sub>j</sub> = 150 °C; Fig. 10; Fig. 11	-	-	29	mΩ
R <sub>G</sub>	gate resistance	f = 1 MHz	0.68	1.37	2.74	Ω
Dynamic cha	aracteristics		'			
Q <sub>G(tot)</sub>	total gate charge	I <sub>D</sub> = 5 A; V <sub>DS</sub> = 15 V; V <sub>GS</sub> = 10 V; Fig. 12; Fig. 13	-	9.5	-	nC
		I <sub>D</sub> = 5 A; V <sub>DS</sub> = 15 V; V <sub>GS</sub> = 4.5 V; Fig. 12; Fig. 13	-	4.6	-	nC
		I <sub>D</sub> = 0 A; V <sub>DS</sub> = 0 V; V <sub>GS</sub> = 10 V	-	8.4	-	nC
$Q_{GS}$	gate-source charge	I <sub>D</sub> = 5 A; V <sub>DS</sub> = 15 V; V <sub>GS</sub> = 4.5 V;	-	1	-	nC
Q <sub>GS(th)</sub>	pre-threshold gate- source charge	Fig. 12; Fig. 13	-	0.3	-	nC
Q <sub>GS(th-pl)</sub>	post-threshold gate- source charge		-	0.7	-	nC
$Q_{GD}$	gate-drain charge		-	1.7	-	nC
$V_{GS(pl)}$	gate-source plateau voltage	I <sub>D</sub> = 5 A; V <sub>DS</sub> = 15 V; <u>Fig. 12</u> ; <u>Fig. 13</u>	-	2.4	-	V

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C <sub>iss</sub>	input capacitance	$V_{DS} = 15 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$	-	430	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C; <u>Fig. 14</u>	-	120	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	70	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS} = 15 \text{ V}; R_L = 3 \Omega; V_{GS} = 4.5 \text{ V};$ $R_{G(ext)} = 5 \Omega$	-	6.1	-	ns
t <sub>r</sub>	rise time		-	7.2	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	10.1	-	ns
t <sub>f</sub>	fall time		-	5.1	-	ns
Q <sub>oss</sub>	output charge	$V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 ^{\circ}\text{C}$	-	2.3	-	nC
Source-dr	ain diode		<u> </u>			
$V_{SD}$	source-drain voltage	$I_S = 5 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}; Fig. 15$	-	0.89	1.1	V
t <sub>rr</sub>	reverse recovery time	$I_S = 5 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$	-	13.5	-	ns
Q <sub>r</sub>	recovered charge	V <sub>DS</sub> = 15 V	-	5.1	-	nC
t <sub>a</sub>	reverse recovery rise time	$V_{GS} = 0 \text{ V}; I_S = 5 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s};$ $V_{DS} = 15 \text{ V}; Fig. 16$	-	6.3	-	ns
t <sub>b</sub>	reverse recovery fall time		-	7.2	-	ns

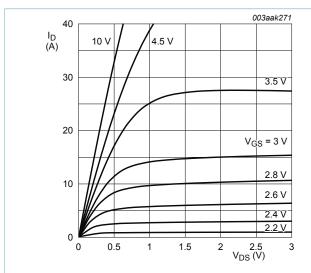


Fig. 6. Output characteristics; drain current as a function of drain-source voltage; typical values

 $T_j = 25$ °C

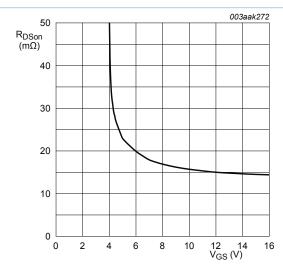


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

 $T_j = 25^{\circ}C; I_D = 10A$ 

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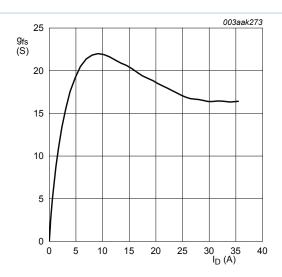


Fig. 8. Forward transconductance as a function of drain current; typical values

$$T_j = 25^{\circ}C; \ V_{DS} = 10V$$

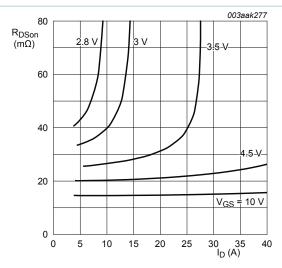


Fig. 10. Drain-source on-state resistance as a function of drain current; typical values

$$T_j = 25$$
° $C$ 

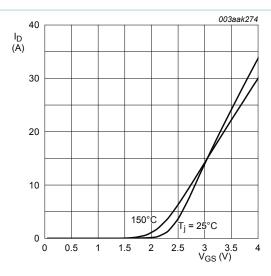


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

$$V_{DS} = 10V$$

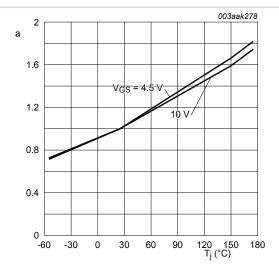


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon}}$$

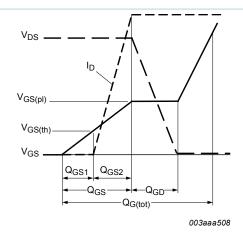


Fig. 12. Gate charge waveform definitions

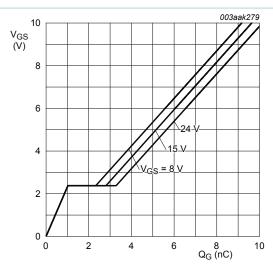


Fig. 13. Gate-source voltage as a function of gate charge; typical values

$$T_j = 25^{\circ}C; I_D = 10A$$

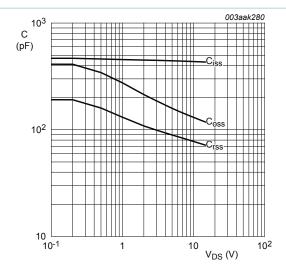


Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

$$V_{GS} = \mathbf{0}V; \ f = \mathbf{1}MHz$$

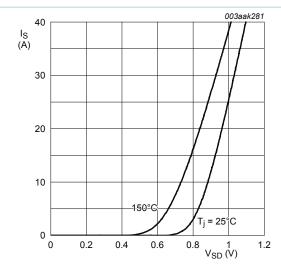
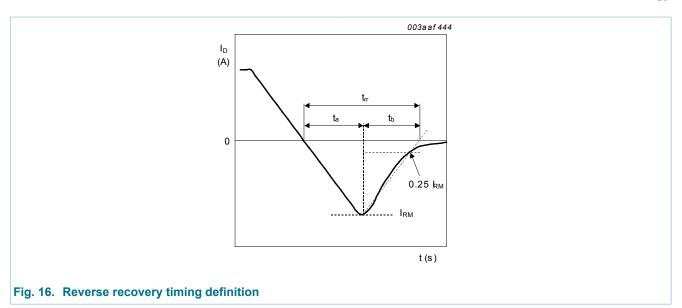
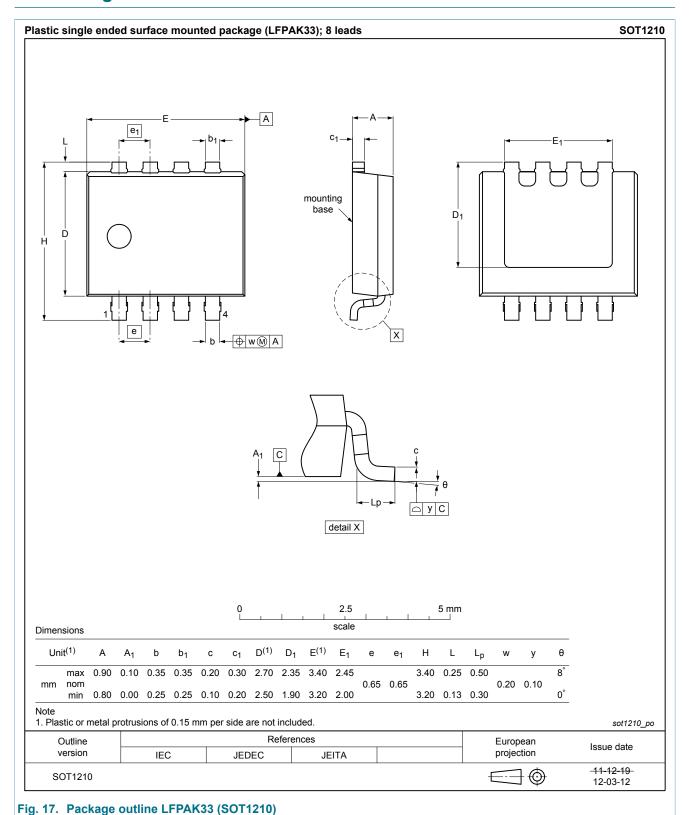


Fig. 15. Source current as a function of source-drain voltage; typical values

$$V_{GS} = 0V$$



### 7. Package outline



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### 8. Legal information

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